Amendments to the Claims:

1. (currently amended) A process for preparing a substrate having alignment features for optical to facilitate passively mounting components on said substrate, said substrate having an x, y, z, orientation and a substrate surface along an xz plane, said substrate having a specific point thereon, said process comprising:

applying a stop etch mask to <u>asaid</u> substrate, said mask defining the location on said substrate of <u>a groove for receiving said waveguide</u> and one or more fiducials for positioning <u>said optical</u> <u>a</u> device on said substrate relative to said <u>specific</u> point <u>waveguide</u>; and

etching said substrate to define said fiducials and said groove using an inductively coupled plasma etching process, at least one of said fiducials comprising a planar surface substantially perpendicular to said substrate surface, said planar surface being adapted to act as a register surface to said groove being dimensioned to receive at least a portion of a waveguide and said fiducials enablinge said optical device to be positioned on said substrate such that it is in a precise position relative to said specific point optically aligned with said waveguide.

2. (canceled)

- 3. (currently amended) The process of claim $2\underline{1}$, wherein said inductively coupled plasma etching process is a Bosch process.
- 4. (currently amended) The process of claim ± 25 , wherein at least one of said fiducials comprises a planar surface substantially perpendicular to said substrate surface, and said groove is deeper than $13\mu m$ from said substrate surface.
- 5. (previously presented) The process of claim 4, wherein said groove is a U-groove.

- 6. (previously presented) The process of claim 5, wherein said U-groove has a bottom at about 60 to about $65\mu m$ from said substrate surface.
- 7. (previously presented) The process of claim 6, wherein etching said U-groove comprises etching a U-groove terrace, said U-groove and U-groove terrace defining edges for receiving a waveguide.
- 8. (previously presented) The process of claim 1, wherein said substrate is form from a materials selected from the group consisting of polycrystalline silicon, silica, and ceramics.
- 9. (previously presented) The process of claim 1, further comprising etching an etched field encompassing said fiducials.
- 10. (previously presented) The process of claim 1, wherein a first fiducial defines a first register surface a first certain distance from said substrate surface along said y-axis, a second fiducial defines a second register surface a second certain distance from said specific point along said x-axis, a third fiducial defines a third register surface a third certain distance from said specific point along said z-axis, and wherein said groove, and said first, second and third fiducials are located on said substrate using the same mask.
- 11. (currently amended) The process of claim 1025, wherein a first fiducial defines a first register surface a first certain distance from said substrate surface along said y-axis, a second fiducial defines a second register surface a second certain distance from said specific point along said x-axis, a third fiducial defines a third register surface a third certain distance from said specific point along said z-axis, and wherein said groove, and said first, second and third fiducials are located on said substrate using the same mask, and wherein a mechanical stop has a fourth register surface a fourth certain distance from said specific point along said z-axis, said mechanical stop being adjacent to said groove and adapted to contact a waveguide in said groove to position it from said specific point along the z-axis.

- 12. (currently amended) The process of claim †25, wherein a mechanical stop has a fourth register surface a fourth certain distance from said specific point along said z-axis, said mechanical stop being adjacent to said groove and adapted to contact a waveguide in said groove to position said waveguide from said specific point along the z-axis.
- 13. (previously presented) The process of claim 1, further comprising disposing an optical device on said substrate in a certain position relation with respect to said fiducials.
- 14. (previously presented) The process of claim 13, wherein optical device is disposed on said substrate by visually aligning said optical device to said fiducials.
- 15. (previously presented) The process of claim 13, wherein said optical device is disposed on said substrate by physically contacting said optical device with said fiducials
- 16. (previously presented) The process of claim 13, wherein further comprising disposing a waveguide in said groove
- 17. (previously presented) The process of claim 1, wherein the tolerance of the alignment of said groove to said fiducials is less than $\pm 0.2~\mu m$.
- 18. (currently amended) The process of claim ±25, wherein said waveguide is a fiber.
- 19. (previously presented) The process of claim 1, wherein said optical device is at least one of a laser, photodetector, or monitor.
- 20. (withdrawn) A substrate formed according to the process of claim 1.
- (withdrawn) An optical component substrate comprising:
 a groove for receiving a waveguide; and
 fiducials for facilitating the alignment of an optical device on said substrate;

wherein the tolerance of the alignment of said groove to said fiducials is less than $\pm 0.2 \mu m$.

22. (withdrawn) An optical subassembly comprising: an optical component substrate comprising at least:

a groove for receiving a waveguide; and fiducials for facilitating the alignment of an optical device on said substrate; wherein the tolerance of the alignment of said groove to said fiducials is less than $\pm 0.2 \mu m$.

a waveguide disposed in said groove; and an optical device aligned with said fiducials.

- 23. (withdrawn) The optical subassembly of claim 22, wherein said optical device is a laser.
- 24. (withdrawn) A transceiver comprising the optical subassembly of claim 23.
- 25. (new) The process of claim 1, wherein said device is an optical device and wherein said mask also defines the location on said substrate of a groove for receiving said waveguide, and wherein said grove is also etched using an inductively coupled plasma etching process.
- 26. (new) The process of claim 25, wherein, when said optical device is in said precise position, it is optically aligned with said wave guide.
- (new) The process of claim 1, further comprising:effecting the positioning of said device against said register surface.
- 28. (new) The process of claim 27, wherein said device is within $\pm 0.2~\mu m$ of said precise position